Vortex-like excitations in a non-superconducting single-layer compound $Bi_{2+x}Sr_2 CuO_{6+}$ single crystal in high magnetic elds

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The in-plane $_{ab}(H;T)$ and the out-of-plane $_{c}(H;T)$ magneto-transport in magnetic elds up to 28 T has been investigated in high quality non-superconducting (down to 20 mK) La-free $Bi_{2+x}Sr_{2-x}CuO_{6+}$ single crystal. By measuring the angular dependence of the in-plane and out-of-plane magnetoresistivities at temperatures from 1 K down to 30 mK, we present evidence for the presence of vortex-like excitations in a non-superconducting cuprate in the insulating state. Such excitations have previously been observed by the detection of a Nemst signal in superconducting cuprates at T > T_c in magnetic elds.

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I. IN TRODUCTION

O riginating from the pioneering experiments of Uem ura et al.¹ there is now a general consensus concerning the determ ining factor for the critical tem perature (T_c) in high- T_c superconductors. In R ef.[1] it was shown that T_c is proportional to the zero-tem perature superconducting carrier density for a wide range of underdoped materials. This correlation is a consequence of the proximity to the M ott transition.² In conventional superconductors, the destruction of superconductivity begins with the breakup of electron pairs. However, in cuprates with increasing tem perature, therm al excitations will destroy the ability of the superconductor to carry a supercurrent whereas the pairs can continue to exist.³

At present, there is growing evidence that the transition out of the superconducting state is caused by the proliferation of vortices, which destroy long-range phase coherence. The detection of a large N emst signal above T_c has provided evidence for the vortex scenario.^{3,4,5,6,7} R ecently, Sandu et al.⁸ have shown that the m easured in-plane angular dependence of the magnetoresistance on Y_{1 x} Pr_xBa₂Cu₃O₇ single crystals with 35 K T_c 92 K is consistent with a ux- ow type contribution. This is again an indication of the presence of vortex-like excitations above T_c in the pseudogap region.

However, in Ref. [9], it has been suggested that the large N emst signal observed above T_c is due to superconducting uctuations in the normal state. Very recently, A lexandrov and Zavaritsky¹⁰ calculated the expected N emst signal in disordered conductors and showed that a strong N emst signal is unrelated to vortices or a superconducting pair scenario. They found instead, that the N emst signal could arise from the interference of itinerant and localized-carrier contributions to the therm om agnetic transport.

Therefore, whether these phenom ena are a result of the presence of vortices above the zero-eld critical tem perature remains an open question. Our magnetoresistance investigation of a non-superconducting single crystal at tem perature down to 30 mK should help to distinguish between these di erent points of view because magnetoresistance is a potentially incisive probe of the hole dynam ics. In this paper we present, to our know ledge, the rst evidence for vortices in a non-superconducting cuprate from angular magnetoresistance measurements on La-free, high quality B i_{2+x} Sr₂ x CuO ₆₊ (B i2201) single crystals. Transport and magnetotransport in nonsuperconducting B i2201 crystals have been investigated long ago (see e.g. R efs. [11,12,13,14]), how ever, magnetoresistance and the angular dependence of the magnetoresistance at mK tem peratures was not studied.

In previous measurements¹⁵ we have investigated the in-plane $_{ab}(H;T)$ and the out-of-plane $_{c}(H;T)$ magneto-transport in magnetic elds up to 28 T in a series of superconducting Bi2201 single crystals over a wide doping range and over a wide range of tem peratures down to 40 mK. The T_c (m idpoint) values of the crystals lay in the region 2:3 9:6 K.W ith decreasing carrier concentration per Cu atom (p), going from the overdoped (p = 0.2) to the underdoped (p = 0.12) regimes, a crossover from a metallic to an insulating behavior of ab (T) was observed in the low temperature norm alstate, resulting from a disorder induced m etal insulator transition. Note that, throughout this paper, by insulating phase we simply mean that the resistivity has the tem perature dependence of an insulator (d = dT < 0) rather than a m etal (d = dT > 0). The investigation spresented in this paper are an extension of these studies to the non-superconducting region of the H T phase diagram . W e used a 28 T resistive m agnet at the G renoble High M agnetic Field Laboratory, in order to measure the in-plane and out-of-plane m agnetoresistance with various eld orientations relative to the ab-plane of the crystal.

II. EXPERIMENT

The preparation and characterization of Bi2201 single crystals are described in detail elsewhere.¹⁵ Here we

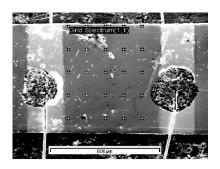


FIG. 1: Scanning electron m icrograph of the investigated crystal between voltage contacts where the composition m easurem ent points are denoted by crosses.

have characterized three as-grown single crystals which have been grown in the same crucible and found that sam ples are of high quality with alm ost identical characteristics. To investigate the low tem perature m agnetotransport behavior, we selected the best crystal. The crystal was cut to have the approxim ate dimensions of 0:7 mm 10 m. The actual cationic composi-1**:**9 m m tion of the selected sample was measured at 40 di erent points on the crystal and the scatter in the data was less than 2% . Figure 1 shows the scanning electron micrograph of the crystal between the voltage contacts (gold $\ensuremath{\mathsf{lm}}$, a silver pad and gold wires) where the composition measurement points are denoted by crosses. We estimate the carrier concentration in the sample to be p = 0.09 by using the empirical relation between the Bi excess, x, and p.^{15,16} Optim um doping in this system occurs around p ' 0:17 and the T_{c} (p) dependence shows a faster drop in the underdoped side of the phase diagram. The superconducting phase in B 2201 extends only down to p = 0.11.¹⁵ The error associated with the carrier concentration estim ation is less than 4% (see Fig.1 in Ref. [17]). Thus, our sample with p = 0.09 is de nitely located below the superconductor-insulator phase transition, heavily underdoped and non-superconducting.15 The half-width of the sublattice re ections in the Xray rocking curves for this crystal did not exceed 0:15 . These data clearly dem onstrate the high structural quality and high hom ogeneity of the sample on a microscopic scale.

A four-probe contact con guration, with symmetrical positions of the low -resistance contacts (< 1) on both ab-surfaces of the sam ple was used for the measurements of R_{ab} and R_c resistances. The temperature and magnetic eld dependence of the resistances R_{ab} (T;H) and R_c (T;H) were measured using a lock-in amplier driven at 10.7 Hz. For the low temperature magnetotransport measurements, the crystalwas placed directly inside the mixing chamber of a top-loading dilution fridge. For the in-plane transport current J, a con guration with H? J was used in all cases. In the angular magnetoresistance measurements for the out-of-plane transport current, the magnetic eld direction changed from the longitudinal (H k c k J) to transverse (H ? c k J) con-

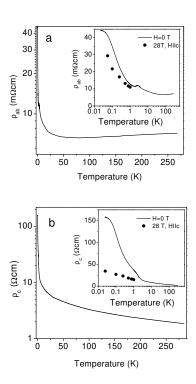


FIG.2: Temperature dependence of the in-plane $_{ab}$ (a) and out-ofplane $_{c}$ (b) resistivities for the investigated B i2201 single crystal. Note the log scale for the vertical axis. The insets plot $_{ab}$ (T) and $_{c}$ (T) with the horizontal axis plotted using a logarithm ic scale in order to emphasize the low-temperature behavior.

gurations. The angular resolution was better than 03 . The ac current applied was 5 A for in-plane and 10 A for out-of-plane resistance m easurements. A RuO₂ therm on eter was used to m easure the local temperature of the sample. The eld sweep rate dH =dt = 0.5 T/m in at temperatures 30 150 mK and 1 T/m in at higher temperatures was chosen in order to avoid eddy current heating. The temperature was continuously recorded during each m easurement sweep.

III. IN -P LANE [ab (T)] AND OUT -OF -P LANE [c (T)] RESIST IV IT IES

In Fig 2 (m ain panels) we show the tem perature dependence of the in-plane $_{ab}$ (a) and out-ofplane $_{c}$ (b) resistivities for the investigated B i2201 single crystal, with the vertical axis plotted using a logarithm ic scale. The insets in Fig 2 plot $_{ab}$ (T) and $_{c}$ (T) with a logarithm ic scale for the horizontal axis in order to emphasize the low-tem perature behavior. The data points (closed circles) show the resistivity data at H = 28 T with the m agnetic eld parallel to the c-axis. Figure 2 clearly dem onstrates that at zero m agnetic eld, the sam ple rem ains in its a norm al state down to 20 m K. $_{ab}$ in the high-tem perature range shows a weak m etallic behavior

 $(d_{ab}=dT > 0)$, goes through a minimum at temperature Т 70 K and then shows an insulating behavior, consistent with the onset of localization. $_{c}(T)$ in Fig.2(b) increases as log (1=T) as the tem perature decreases from the room temperature down to T 5 K and then trans– forms to an insulating behavior. At ultra low temperatures, T = 0.02 0.1 K, _{ab} and _c show a downward deviation (saturation) from the insulating behavior. Such deviation from a log (1=T) dependence of the in-plane and out-of-plane resistance of B i2201 in norm al state at ultra low tem peratures has been studied in detail in R ef. [15]. As can be seen in Fig.2(a), at zero magnetic eld, there is the weak uptum in the region 2 3 K, which in reference [15], was attributed to a competition between the onset of superconductivity and localization. A weak feature in this tem perature region is also observed in $_{\rm c}$ (T) (Fig.2(b)).

A strong 28 T m agnetic eld in the perpendicular geom etry barely suppresses the localization and therefore, the insulating behavior of $_{ab}$ persists [Fig.2(a)] as in the case of underdoped crystals in Ref. [15]. W hereas the e ect of the high magnetic eld on $_{\rm c}$ is very noticeable. The insulating behavior of the $_{\rm c}$ (T) dependence at low tem peratures is signi cantly suppressed and $_{\rm c}$ (T) shows an alm ost identical log (1=T) dependence over the whole tem perature range [Fig 2 (b)] that can be interpreted as the magnetic-eld induced suppression of localization. The behavior of the resistivities described above is in agreem ent with our previous results for B i2201 single crystals in the magnetic-eld induced norm al state¹⁵ and completes the crossover picture from a metallic to an insulating behavior of $_{ab}$ (T) and $_{c}$ (T) with decreasing hole concentration.

IV. IN-PLANE MAGNETORESISTIVITY [ab (H)]

Returning now to the magnetoresistance curves, we immediately encounter an anomaly. Figure 3 (main panel) displays the transverse in-planem agnetoresistance ab (H) for the sam e B i2201 sam ple at various tem peratures from 55 mK to 1 K with the magnetic eld perpendicular to the ab-plane. At each temperature, the magnetic eld dependence shows a crossover from positive magnetoresistance at low magnetic eld to negative magnetoresistance at higher magnetic elds. As can be seen, the resistivity starts to rise rapidly from the zero-eld value, reaches a maximum at the peak eld, H $_{\rm peak}$, and then decreases sharply with increasing magnetic eld. Thereafter, the slope d ab=dH changes and becomes small at high eld. This behavior points clearly to the presence of two di erent mechanisms responsible for the negative magnetoresistance in Fig. 3. W ith increasing temperature, the maximum in $_{ab}(H)$ shifts toward lower magnetic eld and the amplitude of the maximum decreases monotonically. It is signi cant that at low tem perature (55 mK) the relative variation $_{ab} = _{ab0} = [_{ab} (H;T)]$ _{ab}(0;T)⊨ _{ab}(0;T) is asmuch

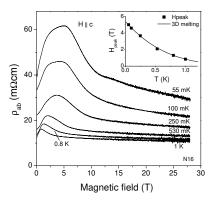


FIG. 3: Transverse in-plane m agnetoresistance for Bi2201 sample at various temperatures from 55 m K to 1 K with the m agnetic eld perpendicular to the ab-plane. The inset is the m agnetic eld position of the maxim a $_{\rm ab}$ (H) (squares) versus the temperature. The solid line is a t to the experimental points using the expression (1) in Ref. [18] for an irreversibility line of our low -T_c Bi2201 single crystals that corresponds to the melting of a three-dimensional vortex lattice (see text below).

as + 55% at the peak eld (positive m agnetoresistance) and -30% at 28 T (negative m agnetoresistance) in the transverse con guration of the m agnetic eld. It should be especially emphasized that the sharp change in the slope d $_{\rm ab}$ =dH in the isotherm s occurs at the resistivities near the zero- eld values.

For high-T_c superconductors, a small positive transverse and quadratic in-plane m agnetoresistance has been observed in $T_{2}Ba_{2}CuO_{6+}$ (3% at 60 T and 130 K, 80 K $)^{19}$ and Bi2201 (12% at 8 T and 5 K , $T_{\rm c}$ = T_c 3 4 K).²⁰ However, $_{ab}$ in Fig.3 shows a much stronger positive m agnetoresistance com pared to reported experi-_{ab}= _{ab0} does not show a quadratic m ental results and dependence on magnetic eld. In quasi-classical models of conventional metals a spin-dependent scattering leads to a very small (=10³) positive magnetoresistance. It is known also that the spin-dependent scattering leads to a positive magnetoresistance that is independent of the applied eld orientation with respect to the current direction. Thus, a priori, the transverse magnetoresistance, in addition to the orbital contribution, may also contain a Zeem an contribution (actually, this is probably not the case, see below).

To understand the origin of the orbital contribution to the transverse in-plane m agnetoresistance in our sam ple, we have studied the angular dependence of the in-plane m agnetoresistance. Figure 4 displays the in-plane resistivity as a function of applied eld for various m agnetic eld orientations relative to the ab-plane of the crystal, m easured at 0.25 (a) and 0.5 K (b). We can clearly see a considerable di erence in the eld position of the m axim um in $_{ab}$ (H) between the perpendicular (= 90) and parallel (= 0) con gurations of the m agnetic eld. Since, in both eld directions, the m agnetoresistance is transverse, the highly anisotropic response points

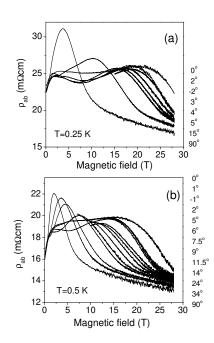


FIG.4: In-plane resistivity as a function of applied eld for various magnetic eld orientations relative to the ab-plane of the crystal, measured at 0.25 (a) and 0.5 K (b).

to the importance of orbitale ects for the magnetoresistance. This probably excludes any explanation of the positive in-plane magnetoresistance in terms of spin effects. However the large anisotropy is restricted to the region of the peak (the bell-shaped part of the curves) in $_{ab}(H)$. As can be seen from Fig.4, at higher magnetic elds, where $_{ab}(H)$ shows a small negative magnetoresistance, the curves remain almost unchanged as the sample is rotated. Most likely, the high magnetic eld region for which d $_{ab}$ =dH is small and negative in Fig.3 and Fig.4, corresponds to the negative transverse in-plane magnetoresistance reported in earlier investigations of non-superconducting B i2201 single crystals.¹⁴

The previously reported negative in-plane m agnetoresistance was quite sm all (near 5% at 0.45K and 8T).¹⁴ The magnetoresistance was negative in the temperature range 0.45-20 K and becam e positive with increasing tem perature above 20 K . To account for these results, the authors invoked localization theory $_{\prime}^{21}$ which describes the low -tem perature negative m agnetoresistance in m etals in a weak-localization regime. The negative magnetoresistance resulted from the magnetic eld induced suppression of localization e ects. In zero magnetic eld, samples showed an insulating behavior of $_{\rm ab}$ (T) for T < 20 K, where localization e ects should be im portant, especially at very low tem peratures. A lthough the negative in-plane m agnetoresistance observed at high m agnetic elds in Fig.3 is considerably larger than that observed in Ref. [14] (due to ultra low tem peratures), our results are in agreem ent with these experim ents and it is reasonable to assume that they have the same physical origin.

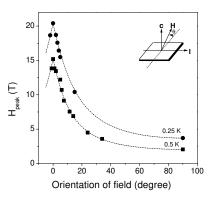


FIG. 5: A ngular dependence of the eld position of the maximum of $_{ab}(H)$ (H $_{peak}$) at the temperatures 0.25 and 0.5 K extracted from the magnetoresistance curves in Fig.4. D ashed lines are ts to experimental data using T inkham's relation with an isotropy parameter = H $_{c2}^{kab}$ equals to 5.5 at T = 0.25 K and 7.4 at T = 0.5 K.

Turning now our attention to the origin of the bellshaped part of magnetoresistance, we would like to note that in layered superconductors, the anisotropy of the magnetoresistance is a direct consequence of the anisotropy of the upper critical eld H_{c2} . In such superconductors with a high degree of anisotropy, a twodimensional situation with decoupled layers arises and for the angular dependence of H_{c2} it is possible to use T inkham's relation for a thin- Im superconductor in the vicinity of T_c ,²²

$$jH_{c2}()sin = H_{c2}^{?ab}j + [H_{c2}()cos = H_{c2}^{kab}]^{2} = 1;$$
 (1)

In Fig.5, we show the angular dependence of magnetic eld position of the maximum of $_{ab}$ at the temperatures 0.25 and 0.5 K extracted from the magnetoresistance of the crystal in Fig.4. D ashed lines are ts to the data using T inkham's relation, with anisotropy parameter = H $_{c2}^{kab}$ =H $_{c2}^{2}$ equal to 5.5 at T = 0.25 K, and 7.4 at T = 0.5 K. As can be veriled from Fig.5, the magnitudes 5.5 and 7.4 are simply equal to the ratio of the eld position of the $_{ab}$ (H) maxima at = 0 and = 90. The experimental points in Fig.5, show a cusp-like behavior at = 0 with dH $_{c2}$ =d € 0, in good agreement with the prediction of the thin- Im model (dashed lines). This cusp-like behavior has previously been observed in superconducting multilayers.^{23,24}

A lthough T inkham 's model predicts a tem peratureindependent critical eld anisotropy, a tem perature dependence is experimentally observed in layered superconducting single crystals $.^{24,25,26}$ For comparison, we show in Fig.6 the resistive upper critical eld H $_{\rm c2}$ as a function of the angle between the magnetic eld and ab-plane at T = 0:7 K extracted from the magnetic eld-induced transitions of one of our superconducting slightly underdoped B i2201 single crystals with T_c = 6 7.5 K. The different sym bols are the experimental H $_{\rm c2}$ values obtained from the elds at which the resistivity of the sam ple has reached 1%, 10% and 50% of it normal-state value $_{\rm n}$.

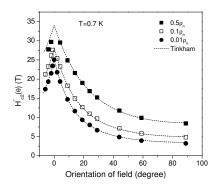


FIG. 6: The resistive upper critical eld H $_{\rm c2}$ as a function of the angle between the magnetic eld and ab-plane at T = 0:7 K extracted from the magnetic eld-induced transitions of our superconducting slightly underdoped B i2201 single crystal with T_c = 6 7.5 K. The di erent symbols are the experimental H $_{\rm c2}$ values obtained from the elds at which the resistivity of the sample has reached 1%, 10% and 50% of it norm al-state value $_{\rm R}$.

Some data points are m issing, because of the very large values of the upper critical elds in the H kab geometry (=0) at this temperature, we are unable to determ ine H _{c2} values using the 50% norm al-state resistivity criterium. Again, the experimental data, which shows a cusp-like behavior at = 0, is in good agreement with the prediction of T inkham's form ula (dashed lines).

In our opinion, Figs.3 – 6 demonstrate clearly that the observed positive in-plane magnetoresistance in $_{ab}$ (Fig.3) is associated with superconductivity and them aximum in $_{ab}$ (H) at low temperatures is close to some \upper critical eld". However admittedly, the explanation of the maximum itself in $_{ab}$ (H), in particular the bellshaped form of the magnetoresistance curves in Fig.3 is not fully understood.

In the inset of Fig.3 we show the magnetic eld position of the maxim a ab (H) (squares) versus the tem perature. The solid line is a t to the experimental data using expression (1) in Ref. [18] for the irreversibility line of our low-T_c superconducting Bi2201 single crystals which corresponds to the 3D-2D melting of a vortex lattice. Here we have used the fact that at very low tem peratures the melting eld and the upper critical eld $coincide^{27}$. The t shown in the inset of Fig.3 is made xing $T_c = 2.45$ K (the onset of the weak uptum in Fig.2 (a)) and leaving H $_{\rm c2}$ (0) and $c_{\rm L}^2$ m =Gias free param eters. Here c_L , m 5:6 and Giare the Lindem ann num ber, a num erical factor and the G inzburg num ber, respectively.¹⁸ From the twe obtain $H_{c2}(0) = 5:4$ T and $c_{\rm L}^2$ $_{\rm m}$ =Gi = 0:37. The value of H $_{\rm c2}$ (0) is close to the experimental magnitude $H_{peak} = 5 T$ at T = 55 m Kand $c_{\rm f}^2$ m =G i closely m atches the value found in Ref. [18] taking into account the di erence in $H_{c2}(0)$ ". This is indicative of the presence of a vortex state in the nonsuperconducting sample in magnetic eld. In this case, them aximum and negativem agnetoresistance in the bellshaped part of $_{ab}$ (H) in Fig.3 can be explained by the fact that at high magnetic elds, the number of regions able to support vortices decreases with increasing magnetic eld, and therefore, the dissipation decreases.

A linear extrapolation to high tem peratures of the am – plitude of the maximum $_{\rm ab}$ plotted on a log scale as a function of tem perature (not shown) from Fig.3, shows that the vortex-like excitations have to vanish at a critical tem perature T $_{\rm 4}$ 5 K . Hence, using $T_{\rm c}$ = 2:45 K for our sample gives $1.5T_{\rm c}$ < T $_{\rm <}$ 2T $_{\rm c}$. This is consistent with the existence of vortex-like excitations in the pseudogap region, up to a tem perature T , that manifest them selves as ux- ow resistivity. 8

Another possible explanation for the bell-shaped magnetoresistance in Fig.3, suggested by the quasitwo-dimensional nature of Bi2201, is a magnetic-eldtuned superconductor-insulator transition. Very recently Steiner et al.²⁸ suggested that the behavior of some high- T_c superconductors at very high magnetic elds is similar to that of am orphous indium oxide (InO x) Im s near the magnetic eld tuned superconductor-insulator transition. A similar magnetoresistance peak at low tem peratures was rst observed by Paalanen et al.²⁹ in am orphous superconducting InO x thin Im s. The authors of Ref.[29] explained this peak by invoking the scaling theory of the superconductor-insulator transition in disorder two-dimensional superconductors.³⁰

In such systems, at su ciently low magnetic elds and at zero tem perature, Cooper pairs are condensed, whereas eld-induced vortices can be localized due to disorder (a vortex glass phase). As the magnetic eld is increased, the system undergoes a superconductorinsulator transition at some critical eld. In the insulating phase, the vortices are delocalized and undergo a condensation, whereas C ooper pairs are localized. Near the transition, there is a competition between condensation of C ooper pairs and vortices. In the vortex-glass phase, long-range crystalline correlations are destroyed by disorder vortex motion at nite tem peratures, giving rise to a nonzero resistance. Further increasing the magnetic eld causes the system to enter a Ferm i-insulator state containing localized single electrons. Experim ental evidence for this picture has been provided by the tem perature and magnetic-eld dependence of the resistance in am orphous InO x $\ln s^{29}$ In order to explain the observed peak in magnetoresistance near the superconductor-insulator transition and the subsequent decrease of the m agnetoresistance, it has been suggested that an insulator with localized C ooper pairs should have a higher resistance than an insulator with localized single electrons.

Steiner et al.²⁸ argued that a local pairing am plitude persists well into the dissipative state of the high- T_c superconductors, the regime commonly denoted as the \norm al state" in very high magnetic eld experiments. They concluded that the superconductor-insulator transition in La_{2 x} Sr_xCuO₄ occurs at a critical eld of the order of the mean-eld upper critical eld H_{c2}(0) where the magnetoresistance maximum at low temperatures

w as observed.³¹ They attributed the m agnetoresistance m axim um to a decrease in the local pair am plitude and a crossover from a Bose-particle dom inated to a Ferm i-particle dom inated system. This means that the large resistance of the sam ple is dom inated by weakly localized pairs, while above the maxim um for $H > H_{c2}(0)$, pairs start to dissociate at a faster rate, giving rise to a negative m agnetoresistance as the system slow ly approaches a state that does not support pairing.²⁸

The magnetoresistance curves presented here in Fig.3 are not strictly identical to those reported for am orphous superconducting InOx Im s^{28,29} in which all isotherm s reach a maximum and then start to decrease at a com mon magnetic eld value. In our sample the magnetic eld position of the maximum magnetoresistance changes with the tem perature. In addition, the resistance of InOx Ims beyond the maximum saturates at high magnetic eld but remains larger by a factor of 1:7 than the zero-eld norm al-state resistance, as extrapolated from the temperature dependent resistance above the transition. W hereas in our case, the magnetoresistance in the bell-shaped part of the curves reaches the zero-eld norm al-state value and further decreases at high magnetic eld (Fig.3). Nevertheless, the behavior of our strong disordering non-superconducting B i2201 sample in the low and moderate magnetic elds with the bell-shaped magnetoresistance is similar to that of thin Ims of am orphous InOx near the magnetic-eldtuned superconductor-insulator transition.^{28,29}. Our interest is in the superconductor-insulator transition in a system with a strong disorder which drives $T_c ! 0$ so that bulk superconductivity is suppressed. W e note that the description of the superconductor-insulator transition above does not take into account the role of unpaired electrons, which are expected to become important when the magnetic eld is high enough to ensure the destruction of the localized pairs. Here, as in Ref. [28], we think that the superconductor-insulator transition in a strongly disordered B i2201 system occurs close to the mean-eld upper critical eld H $_{c2}$ (0) where the magnetoresistance in Fig.3 has maximum.

V. OUT-OF-PLANE MAGNETORESISTIVITY [$_{\rm c}\,({\rm H}\,)$]

In Fig.7 (m ain panel) we plot $_{\rm c}$ versus magnetic eld for the sam e non-superconducting Bi2201 single crystal at various tem peratures from 30 m K to 1 K form agnetic eld perpendicular to the ab-plane (H k c k J). O ne can see that the longitudinal out-of-plane magnetoresistance is negative over the entire magnetic eld region and decreases by alm ost 80% by H = 28 T for T = 30 m K. The negative magnetoresistance in Fig.7 rapidly weakens with increasing magnetic eld and clearly shows a saturation. T hese results are surprising because in heavily underdoped superconducting Bi2201 sam ples, with p = 0:12 and 0.13 (T_c (m idpoint)= 2.3 and 3 K, respectively), after

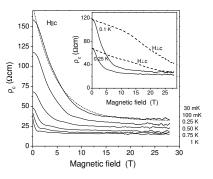


FIG.7: (Main panel) $_{\rm c}$ versus magnetic eld for Bi2201 single crystal at various temperatures from 30 mK to 1 K for magnetic eld perpendicular to the ab-plane (H k c k J). The inset is $_{\rm c}$ (H) curves at temperatures 0.1 and 0.25 K for the longitudinal H k c k J (solid lines) and transverse H ? c k J (dashed lines) con gurations.

the suppression of superconductivity by magnetic ed, $_{\rm c}$ decreases almost linearly with increasing magnetic eld by 10–15% at 28 T and 40 m K 15

It was found in Ref.[15] that such a behavior of c (H) is typical for slightly underdoped, optim ally doped and overdoped superconducting B i2201 sam ples. M oreover, the normal-state out-of-plane magnetoresistance of superconducting samples was independent of the eld orientation with respect to the current direction.³² W hereas, the out-of-plane m agnetoresistance in the nonsuperconducting sample is highly anisotropic. To illustrate this, we show in the inset of Fig.7 the $_{c}(H)$ curves at tem peratures 0.1 and 0.25 K for the longitudinal H k c k J (solid lines) and transverse H ? c k J (dashed lines) con gurations. As in the case of the inplane magnetoresistance in Fig.4, there is a large difference between the out-of-plane m agnetoresistance behavior for two magnetic eld orientations relative to the ab-plane of the crystal. This is further evidence that the observed out-of-plane m agnetoresistance of the nonsuperconducting sample may be associated with the superconductivity.

As the response of a superconductor should be to the orbital e ect of a magnetic eld, we assume following Jing et al,¹⁴ that the longitudinalm agnetoresistance involves the spin degrees of freedom alone, and that these contributions are isotropic. Then the orbital contribution to the transverse magnetoresistance may be obtained by subtracting the longitudinalm agnetoresistance from the transverse, i.e. orb = $_{\rm L}$. Here Т $_{c}(0;T) \models _{c}(0;T)$. In Fig.8 we $T_{T,L} = [C(H;T)]$ display the orbital components of the transverse out-ofplane m agnetoresistance at tem peratures 0.1 and 0.25 K extracted from the data in the inset of Fig.7. The curves in Fig.8 are remarkably similar to the broad interlayer resistive transitions of the superconducting B i2201 single crystals in the transverse con guration of the magnetic eld (H ? c k J). For comparison, we show in the inset ofFig.8 the eld dependence of the out-of-plane resistiv-

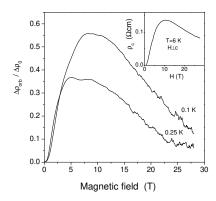


FIG. 8: O ibital components of the transverse out-ofplane m agnetoresistance at temperatures 0.1 and 0.25 K extracted from the data in the inset of Fig.7. The inset displays the eld dependence of the out-ofplane resistivity $_{\rm c}$ in the transverse conguration for our optimally doped Bi2201 single crystal with $T_{\rm c}=9.5$ K (m idpoint).³²

ity $_{\rm c}$ in the transverse con guration for our optimally doped B i2201 single crystal with T_c (m idpoint)= 9:5 K 32

Turning back to Fig.7 (main panel), we see that the out-of-plane negative m agnetoresistance at ultra low tem peratures rapidly saturates with a characteristic exponential decrease with magnetic eld. The short dashed curve shows a num erical t to the magnetoresistance data at 30 mK calculated using the functional form $_{c}$ (H;T) = $_{c0}$ + a exp (H=bT), where a and b are constants. In previous m easurem ents¹⁵ we have pointed out that this Zeem an-like expression describes the anisotropic negative out-of-plane m agnetoresistance in the superconducting B i2201 samples, where, the major contribution to the $_{\rm c}$ (H) curves is due to the gradual decrease of the superconducting gap. If we suggest that a vestige of superconductivity exists in the non-superconducting sam ple, then a com parison of the tem perature-dependent data in Fig.2 (b) with the data in Fig.7, allow sus to conclude that the observed negative m agnetoresistance corresponds to a suppression of the insulating behavior in $_{\rm c}$ (T), which can in turn be interpreted as the magnetic-

eld induced suppression of the superconducting gap. This is simply a consequence of the fact that Cooper pairs exist at low temperatures in our non superconducting sample, while bulk superconductivity is suppressed by strong disorder.

The data in Fig.5 suggest that the \depairing" eld H $_{c2}^{kab}$ in the parallel (= 0) con guration of the magnetic eld at 0.25 K is 20.5 T. In previous m easurem ents^{15,33} we have shown that the maximum in $_{c}$ (H) for B i2201 single crystals does not coincide with H $_{c2}$ and that is positioned near 0.4 $_{ab}^{n}$, where $_{ab}^{n}$ is the norm al-state resistivity in ab-plane. Moreover, the $_{c}$ (H) curves have a pronounced break-point in the derivative well above the $_{c}$ (H) peak. The eld position of these break-points in the derivative coincide with the H $_{c2}$ values determined from the $_{ab}$ (H) curves.³³ As can be seen in Fig.8, the orbital components of the transverse

out-of-plane m agnetoresistance (= 0) at tem perature 0.25 K also start to saturate at H ' 22 T. The fact that $\ \ H_{c2}^{kab}$ m agnitudes" found from the in-plane and out-of-plane m agnetoresistance are in close agreement further supports the presence the vortex-like excitations in the heavily underdoped non-superconducting B i2201 sam ple.

Regarding the large negative longitudinal magnetoresistance we note that an anom alously large negative longitudinalm agnetoresistance (alm ost 90 % at 50 m K and 8 T) has been observed previously in the transition m etal. dichalcogenides³⁴ which also have a layered structure. These compounds show a typical temperature dependence characteristic of variable-range hopping between localized states. Fukuyam a and Yosida³⁵ have explained this phenom enon by introducing Zeem an shifts for the Anderson localized states leading to enhanced conductivity (exponential in $g_B H = k_B T$) with the energy levels of one spin component closer to the mobility edge. Here the g is the Lande g-factor and $_{\rm B}$ is the Bohrm agneton. Since our sample shows an insulating behavior for ab (T) [F ig 2 (a)], we cannot exclude that the large negative longitudinalm agnetoresistance in Fig.7 has the sam e origin as in Ref.[34].

Thus, there are strong grounds to believe that the data above indicates a link between superconductivity and the observed m agnetoresistance of the non-superconducting sam ple. We can form ally exclude m acroscopic sam ple inhom ogeneity, as the origin of the observed phenom ena because the crystal is of a very high quality, judging from the m agnetization m easurem ents, com position analysis and X -ray m easurem ents. The com position of the crystal was studied using a Philips CM -30 electron m icroscopy with a Link analytical AN -95S energy dispersion X -ray spectrom eter that permitted to study sam ple across the whole thickness (10 m). Since the X -ray penetration depth in the X -ray di raction m easurem ents was nearly 6.5 m, the crystal was investigated on both sides. The rocking curve w idth, was also found to be identical.

Taken together, the evidence suggest that at high m agnetic eld, the sample, in an insulating state, is populated by vortices as observed in superconducting cuprates at $T > T_c$ in a magnetic eld, for example, by the detection of a large Nemst signal, 3,4,5,6,7 angular m agnetoresistivity m easurem ents,⁸ and a torque m agnetom etry.³⁶ In a strongly disordered superconductor in zero m agnetic eld at very low tem peratures, localization e ects are strong, long-range phase coherence is destroyed and the superconductivity is suppressed. Nevertheless, a vestige of superconductivity and delocalized vortex-like excitations exist in a magnetic eld.³ Vortex motion at nite tem peratures leads also to a nonzero positive m agnetoresistance (Fig.3 and Fig.4). In the vicinity of the maximum in ab (H) a melting of the vortices occurs resulting in a competition between the positive magnetoresistance and the negative in-plane magnetoresistance that is due to delocalized unpaired electrons. The negative magnetoresistance is also caused by the decrease of the num ber of regions able to support vortices with increasing the magnetic eld. Since the pair amplitude of localized C ooper pairs is very slow ly suppressed out to high magnetic elds, the system retains a vestige of superconductivity at magnetic elds well above H $_{\rm c2}$.²⁸ T he system slow ly approaches a state that does not support pairing where the bell-shaped part of $_{\rm ab}$ (H) curves in Fig.3 is com pleted. Thereafter the negative in-plane m agnetoresistance is due to the magnetic eld dependent localization e ects only.

VI. CONCLUSION

We have presented the temperature dependence for both the in-plane $_{ab}$ (T) and out-of-plane $_{c}$ (T) resistivities and magnetoresistivities $_{ab}$ (H) and $_{c}$ (H) in a high quality non-superconducting (down to 20 mK) La-free B i_{2+x} Sr₂ $_{x}$ CuO $_{6+}$ single crystal. The metallic behavior of $_{ab}$ (T) gradually changes to insulating behavior with decreasing temperature consistent with the onset of localization. $_{c}$ (T) increases as log (1=T) as the temperature decreases from room temperature down to T 5 K and then transform s to an insulating behavior down to 20 mK

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also due to localization. A strong 28 T-m agnetic eld in the perpendicular geom etry barely suppresses of the insulating behavior of $_{\rm ab}$. W hereas magnetic eld e ectively suppresses the insulating behavior in $_{\rm c}$ (T) at low tem – peratures and $_{\rm c}$ (T) shows an almost identical log (1=T) dependence over whole temperature range. Again, this can be interpreted as the magnetic-eld induced suppression of localization. By measuring the angular dependencies of in-plane and out-of-plane magnetoresistivities at temperatures from 1 K down to 30 m K, we have obtained evidence for the presence of vortex-like excitations in a non-superconducting cuprate in the insulating state. Sim ilar vortex-like excitations have been previously observed in superconducting cuprates at T > T_c in magnetic elds by the detection of a Nemst signal.

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